

4-Channel PMBus Power System Manager Featuring Accurate Output Current Measurement

FEATURES

- Sequence, Trim, Margin and Supervise Four Power Supplies
- Manage Faults, Monitor Telemetry and Create Fault Logs
- PMBus Compliant Command Set
- Supported by LTpowerPlay® GUI
- Margin or Trim Supplies to within 0.25% of Target
- Fast OV/UV Supervisors Per Channel
- Fast Output Current Supervisors Per Channel
- Coordinate Sequencing and Fault Management Across Multiple LTC PSM Devices
- Automatic Fault Logging to Internal EEPROM
- Operate Autonomously without Additional Software
- External Temperature and Input Voltage Supervisors
- Accurate Monitoring of Four Output Voltages, Four Output Currents, Four External Temperatures, Input Voltage and Internal Die Temperature
- I²C/SMBus Serial Interface
- Can Be Powered from 3.3V, or 4.5V to 15V
- Available in 64-Lead 9mm × 9mm QFN Package

APPLICATIONS

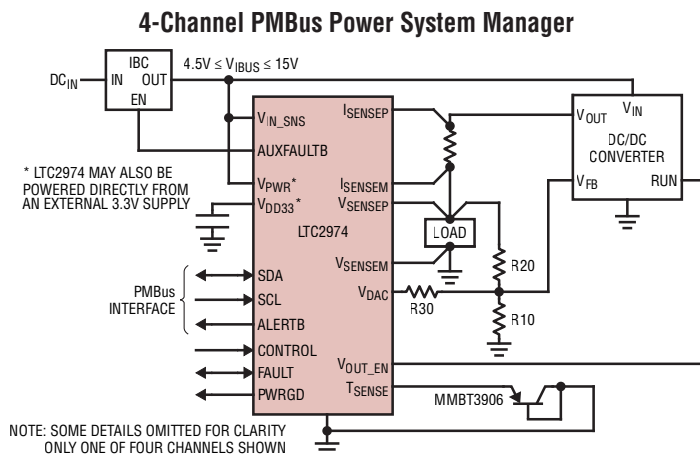
- Computers and Network Servers
- Industrial Test and Measurement
- High Reliability Systems
- Medical Imaging
- Video

DESCRIPTION

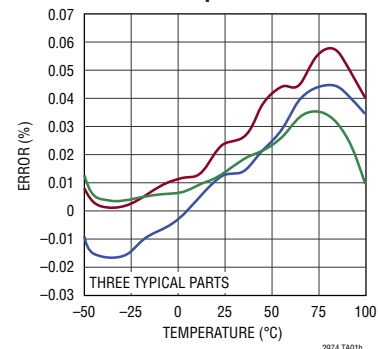
The LTC[®]2974 is a 4-channel Power System Manager used to sequence, trim (servo), margin, supervise, manage faults, provide telemetry and create fault logs. PMBus commands support power supply sequencing, precision point-of-load voltage adjustment and margining. DACs use a proprietary soft-connect algorithm to minimize supply disturbances. Supervisory functions include over and under current, voltage and temperature threshold limits for four power supply output channels as well as over and under voltage threshold limits for a single power supply input channel. Programmable fault responses can disable the power supplies with optional retry after a fault is detected. Faults that disable a power supply can automatically trigger black box EEPROM storage of fault status and associated telemetry. An internal 16-bit ADC monitors four output voltages, four output currents, four external temperatures, one input voltage and die temperature. Output power is also calculated. A programmable watchdog timer monitors microprocessor activity for a stalled condition and resets the microprocessor if necessary. A single wire bus synchronizes power supplies across multiple LTC Power System Management (PSM) devices. Configuration EEPROM with ECC supports autonomous operation without additional software.

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TYPICAL APPLICATION



ADC Total Unadjusted Error vs Temperature



ELECTRICAL CHARACTERISTICS The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at T_J = 25°C. V_{PWR} = V_{IN_SNS} = 12V, V_{DD33}, V_{DD25}, REFP and REFM pins fl **was just +** unless otherwise indicated. C_{VDD33} = 100nF, C_{VDD25} = 100nF and C_{REF} = 100nF. (Note 2)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS	
Sense Input Current Characteristics (Note 11)							
I _{IN_VSENSE}	Input Current	V _{SENSEPN} and V _{SENSEMN} Inputs	●		±15	μA	
	Differential Input Current	V _{SENSEPN} and V _{SENSEMN} Inputs, V _{IN_DIFF} = 6V	●		±30	μA	
I _{IN_ISENSE}	Input Current	V _{SENSEPN} and V _{SENSEMN} Inputs	●		±3	μA	
	Differential Input Current	V _{SENSEPN} and V _{SENSEMN} Inputs, V _{IN_DIFF} = 170mV	●	±0.5	±5	μA	
DAC Output Characteristics							
N_VDAC	Resolution			10			
V _{FS_VDAC}	Full-Scale Output Voltage (Programmable)	DAC Code = 0x3FF DAC Polarity = 1	●	1.3 1.38 2.5 2.65	1.44 2.77	V V	
INL_VDAC	Integral Nonlinearity	(Note 7)	●		±2	LSB	
DNL_VDAC	Differential Nonlinearity	(Note 7)	●		±2.4	LSB	
V _{OS_VDAC}	Offset Voltage	(Note 7)	●		±12	mV	
V _{DAC}	Load Regulation	V _{DACn} = 2.65V, I _{VDACn} Sourcing = 2mA		100		ppm/mA	
		V _{DACn} = 0.1V, I _{VDACn} Sinking = 2mA		100		ppm/mA	
	PSRR	DC: 3.13V ≤ V _{DD33} ≤ 3.47V, V _{PWR} = V _{DD33}		60		dB	
	Leakage Current	V _{DACn} Hi-Z, 0V ≤ V _{DACn} ≤ 6V	●		±100	nA	
	Short-Circuit Current Low	V _{DACn} Shorted to GND	●	-12		-4	mA
	Short-Circuit Current High	V _{DACn} Shorted to V _{DD33}	●	4		12	mA
C _{OUT}	Output Capacitance	V _{DACn} Hi-Z		10		pF	
t _{S_VDAC}	DAC Output Update Rate	Fast Servo Mode		250	500	μs	
Voltage Supervisor Characteristics							
V _{IN_VS}	Input Voltage Range (Programmable)	V _{IN_VS} = (V _{SENSEPN} - V _{SENSEMN})	●	0			
		Low Resolution Mode	●	0		3.8	
		High Resolution Mode	●				
	Single-Ended Voltage: V _{SENSEMN}	●	-0.1		0.1	V	
N_VS	Voltage Sensing Resolution	0V to 3.8V Range: High Resolution Mode		4		mV/LSB	
		0V to 6V Range: Low Resolution Mode		8		mV/LSB	
TUE_VS	Total Unadjusted Error	2V ≤ V _{IN_VS} ≤ 6V, Low Resolution Mode	●			±1.25	
		1.5V < V _{IN_VS} ≤ 3.8V, High Resolution Mode	●			±1.0	
		0.8V ≤ V _{IN_VS} ≤ 1.5V, High Resolution Mode	●			±1.5	
t _{S_VS}	Update Period			12.21		μs	
Current Supervisor Characteristics							
V _{IN_CS}	Current Sense Input Range	Single-Ended Voltage: I _{SENSEPN} , I _{SENSEMN}	●	-0.1		6	
		Differential Voltage: V _{IN_CS} = (I _{SENSEPN} - I _{SENSEMN})	●	-170		170	
N_CS	Current Sense Resolution	I _{OUT_OC_FAULT_LIMIT} • I _{OUT_CAL_GAIN} I _{OUT_UC_FAULT_LIMIT} • I _{OUT_CAL_GAIN}		400		μV/LSB	
TUE_CS	Total Unadjusted Error	50mV ≤ V _{IN_CS} ≤ 170mV	●			±3	
		V _{IN_CS} < 50mV	●			±1.5	
V _{OS_CS}	Offset Error	V _{IN_CS} = 0.8mV	●			±600	
t _{S_CS}	Update Period			12.21		μs	

ELECTRICAL CHARACTERISTICS The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_J = 25^\circ\text{C}$. $V_{PWR} = V_{IN_SNS} = 12\text{V}$, V_{DD33} , V_{DD25} , REFP and REFM pins floating, unless otherwise indicated. $C_{VDD33} = 100\text{nF}$, $C_{VDD25} = 100\text{nF}$ and $C_{REF} = 100\text{nF}$ (Note 2)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS	
V_{IN_SNS} Input Characteristics							
V_{IN_SNS}	V_{IN_SNS} Input Voltage Range		●	0	15	V	
R_{VIN_SNS}	V_{IN_SNS} Input Resistance		●	70	90	110	k Ω
TUE_{VIN_SNS}	VIN_ON, VIN_OFF Threshold Total Unadjusted Error	$3\text{V} \leq V_{VIN_SNS} \leq 8\text{V}$	●		± 2.0	% of Reading	
		$V_{VIN_SNS} > 8\text{V}$	●		± 1.0	% of Reading	
	READ_VIN Total Unadjusted Error	$3\text{V} \leq V_{VIN_SNS} \leq 8\text{V}$	●		± 1.5	% of Reading	
		$V_{VIN_SNS} > 8\text{V}$	●		± 1.0	% of Reading	
DAC Soft-Connect Comparator Characteristics							
V_{OS_CMP}	Offset Voltage	$V_{DACPn} = 0.2\text{V}$	●	± 1	± 18	mV	
		$V_{DACPn} = 1.3\text{V}$	●	± 2	± 26	mV	
		$V_{DACPn} = 2.65\text{V}$	●	± 3	± 52	mV	
External Temperature Sensor Characteristics (READ_TEMPERATURE_1)							
t_{CONV_TSENSE}	Conversion Time	For One Channel, (Total Latency For All Channels Is $4 \cdot 66\text{ms}$)		66		ms	
I_{TSENSE_HI}	T_{SENSE} High Level Current		●	-90	-64	-40	μA
I_{TSENSE_LOW}	T_{SENSE} Low Level Current		●	-5.5	-4	-2.5	μA
TUE_TS	Total Unadjusted Error	Ideal Diode Assumed	●		± 3	$^\circ\text{C}$	
N_TS	Maximum Ideality Factor	$READ_TEMPERATURE_1 = 175^\circ\text{C}$ $MFR_TEMP1_GAIN = 1/N_TS$			1.10		
Internal Temperature Sensor Characteristics (READ_TEMPERATURE_2)							
TUE_TS2	Total Unadjusted Error			± 1		$^\circ\text{C}$	
V_{OUT_ENn} Enable Output ($V_{OUT_EN[3:0]}$) Characteristics							
V_{VOUT_ENn}	Output High Voltage	$I_{VOUT_ENn} = -5\mu\text{A}$, $V_{DD33} = 3.13\text{V}$	●	10	13	14.7	V
I_{VOUT_ENn}	Output Sourcing Current	V_{VOUT_ENn} Pull-Up Enabled, $V_{VOUT_ENn} = 1\text{V}$	●	-5	-7	-9	μA
	Output Sinking Current	Strong Pull-Down Enabled, $V_{VOUT_ENn} = 0.4\text{V}$	●	3	5	8	mA
		Weak Pull-Down Enabled, $V_{VOUT_ENn} = 0.4\text{V}$	●	33	50	65	μA
	Output Leakage Current	Internal Pull-Up Disabled, $0\text{V} \leq V_{VOUT_ENn} \leq 15\text{V}$	●		± 1		μA
V_{VOUT_VALID}	Minimum V_{DD33} when V_{OUT_ENn} Valid	$V_{VOUT_ENn} \leq 0.4\text{V}$	●		1.1	V	
General Purpose Output (AUXFAULTB) Characteristics							
$V_{AUXFAULTB}$	Output High Voltage	$I_{AUXFAULTB} = -5\mu\text{A}$, $V_{DD33} = 3.13\text{V}$	●	10	14.7	V	
$I_{AUXFAULTB}$	Output Sourcing Current	AUXFAULTB Pull-Up Enabled, $V_{AUXFAULTB} = 1\text{V}$	●	-5	-7	-9	μA
	Output Sinking Current	Strong Pull-Down Enabled, $V_{AUXFAULTB} = 0.4\text{V}$	●	3	5	8	mA
	Output Leakage Current	Internal Pull-Up Disabled, $0\text{V} \leq V_{AUXFAULTB} \leq 15\text{V}$	●		± 1		μA
EEPROM Characteristics							
Endurance	(Note 8)	$0^\circ\text{C} < T_J < 85^\circ\text{C}$ During EEPROM Write Operations	●	10,000		Cycles	
Retention	(Note 8)	$T_J < 105^\circ\text{C}$	●	10		Years	
t_{MASS_WRITE}	Mass Write Operation Time (Note 9)	STORE_USER_ALL, $0^\circ\text{C} < T_J < 85^\circ\text{C}$ During EEPROM Write Operations	●		440	4100	ms

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SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
$t_{SU,STO}$	Stop Condition Setup Time (Note 10)		● 600			ns
$t_{HD,DAT}$	Data Hold Time (LTC2974 Receiving Data) (Note 10)		● 0			ns
	Data Hold Time (LTC2974 Transmitting Data) (Note 10)		● 300		900	ns
$t_{SU,DAT}$	Data Setup Time (Note 10)		● 100			ns
t_{SP}	Pulse Width of Spike Suppressed (Note 10)			98		ns
$t_{TIMEOUT_BUS}$	Time Allowed to Complete any PMBus Command After Which Time SDA Will Be Released and Command Terminated	Mfr_config_all_longer_pmbus_timeout = 0	●	25	35	ms
		Mfr_config_all_longer_pmbus_timeout = 1	●	200	280	ms

Additional Digital Timing Characteristics

t_{OFF_MIN}	Minimum Off Time for Any Channel			100		ms
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Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

Note 2: All currents into device pins are positive. All currents out of device pins are negative. All voltages are referenced to GND unless otherwise specified. If power is supplied to the chip via the V_{DD33} pin only, connect V_{PWR} and V_{DD33} pins together.

Note 3: The ADC total unadjusted error includes all error sources. First, a two-point analog trim is performed to achieve a flat reference voltage (V_{REF}) over temperature. This results in minimal temperature coefficient, but the absolute voltage can still vary. To compensate for this, a high-resolution, drift-free, and noiseless digital trim is applied at the output of the ADC, resulting in a very high accuracy measurement.

Note 4: Hysteresis in the output voltage is created by package stress that differs depending on whether IC was previously at a higher or lower temperature. Output voltage is always measured at 25°C , but the IC is cycled to 105°C or -40°C before successive measurements. Hysteresis is roughly proportional to the square of the temperature change.

Note 5: The current sense resolution is determined by the L11 format, the value of $I_{OUT_CAL_GAIN}$, and the magnitude of the current being measured. See Table 2 for details.

Note 6: The nominal time between successive ADC conversions (latency of the ADC) for any given channel is t_{UPDATE_ADC} .

Note 7: Nonlinearity is defined from the first code that is greater than or equal to the maximum offset specification to full-scale code, 1023.

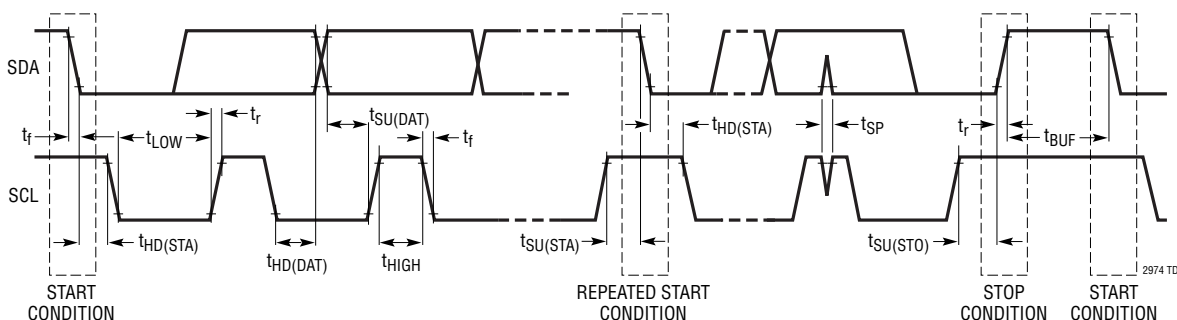
Note 8: EEPROM endurance and retention are guaranteed by design, characterization and correlation with statistical process controls. The minimum retention specification applies for devices whose EEPROM has been cycled less than the minimum endurance specification.

Note 9: Add 74 will not acknowledge any PMBus commands, except for MFR_COMMON, when a STORE_USER_ALL command is being executed. See also OPERATION section.

Note 10: Maximum capacitive load, C_B , for SCL and SDA is 400pF. Data and clock risetime (t_r) and falltime (t_f) are: $(20 + 0.1 \cdot C_B) \text{ (ns)} < t_r < 300\text{ns}$ and $(20 + 0.1 \cdot C_B) \text{ (ns)} < t_f < 300\text{ns}$. C_B = capacitance of one bus line in pF. SCL and SDA external pull-up voltage, V_{I0} , is $3.13\text{V} < V_{I0} < 3.6\text{V}$.

Note 11: V_{SENSE} and I_{SENSE} input currents are characterized by input current and input differential current. Input current is defined as current into a single device pin (see Note 2). Input differential current is defined as $(I^+ - I^-)$ where I^+ is the current into the positive device pin and I^- is the current into the negative device pin.

PMBUS TIMING DIAGRAM



2974fd

OPERATION

LTC2974 OPERATION OVERVIEW

The LTC2974 is a PMBus programmable power supply controller, monitor, sequencer and voltage and current supervisor that can perform the following operations:

- Accept PMBus compatible programming commands.
- Provide DC/DC converter input voltage, output voltage, output current, output temperature, and internal junction temperature readback through the PMBus interface.
- Control the output of DC/DC converters that set the output voltage with a trim pin or DC/DC converters that set the output voltage using an external resistor feedback network.
- Sequence the startup of DC/DC converters via PMBus programming and the CONTROL input pins. The LTC 2974 supports time-based sequencing and tracking sequencing. Cascade sequence on with time based sequence off is also supported.
- Trim the DC/DC converter output voltage (typically in 0.02% steps), in closed-loop servo operating mode, autonomously or through PMBus programming.
- Margin the DC/DC converter output voltage to PMBus programmed limits.
- Trim or margin the DC/DC converter output voltage with direct access to the margin DAC.
- Supervise the DC/DC converter input voltage, output voltage, load current and the inductor temperatures for overvalue/undervalue conditions with respect to PMBus programmed limits and generate appropriate faults and warnings.
- Accurately handle inductor self-heating transients using a proprietary algorithm. These self-heating effects are combined with external temperature sensor readings to improve accuracy of current supervisors and ADC current measurement.
- Respond to a fault condition by continuing operation indefinitely, latching-off after a programmable deglitch period, latching-off immediately or sequencing off after TOFF_DELAY. Use retry mode to automatically recover from a latched-off condition. With retry enabled, MFR_RETRY_COUNT programs the number of retries (0 to 6 or infinite) for all pages.
- Optionally stop trimming the DC/DC converter output voltage after it reaches the initial margin or nominal target. Optionally allow servo to resume if target drifts outside of V_{OUT} warning limits.
- Store command register contents to EEPROM with CRC and ECC through PMBus programming.
- Restore EEPROM contents through PMBus programming or when V_{DD33} is applied on power-up.
- Report the DC/DC converter output voltage status through the power good output.
- Generate interrupt requests by asserting the ALERTB pin in response to supported PMBus faults and warnings.
- Coordinate system wide fault responses for all DC/DC converters connected to the LTC2974 FAULTB0 and FAULTB1 pins.
- Synchronize sequencing delays or shutdown for multiple devices using the SHARE_CLK pin.
- Software and hardware write protect the command registers.
- Disable the input voltage to the supervised DC/DC converters in response to output OV, UV, OC and UC faults.
- Log telemetry and status data to EEPROM in response to a faulted-off condition.
- Supervise an external microcontroller's activity for a stalled condition with a programmable watchdog timer and reset it if necessary.
- Prevent a DC/DC converter from re-entering the on state after a power cycle until a programmable interval (MFR_RESTART_DELAY) has elapsed and its output has decayed below a programmable threshold voltage (MFR_VOUT_DISCHARGE_THRESHOLD).
- Record minimum and maximum observed values of input voltage, output voltages, output currents and output temperatures.
- Access user EEPROM data directly, without altering RAM space (Mfr_ee_unlock, Mfr_ee_erase, and Mfr_ee_data). Facilitates in-house bulk programming.

↑ . Accommodate multiple hosts with Command Plus

↑ Add

PMBUS COMMAND SUMMARY

Summary Table

COMMAND NAME	CMD CODE	DESCRIPTION	TYPE	PAGED	DATA FORMAT	UNITS	EEPROM	DEFAULT VALUE: FLOAT HEX	REF PAGE
USER_DATA_03	0xB3	Scratchpad location.	R/W Word	Y	Reg		Y	0x0000	84
USER_DATA_04	0xB4	Scratchpad location.	R/W Word	N	Reg		Y	0x0000	84
MFR_LTC_RESERVED_1	0xB5	Manufacturer reserved.	R/W Word	Y	Reg		Y	NA	84
MFR_INFO	0xB6	Manufacturer specific information.	R Word	N	Reg			NA	83
MFR_T_SELF_HEAT	0xB8	Calculated temperature rise due to self-heating of output current sense device above value measured by external temperature sensor.	R Word	Y	L11	°C		NA	52
MFR_IOUT_CAL_GAIN_TAU_INV	0xB9	Inverse of time constant for Mfr_t_self_heat changes scaled by $4 \cdot t_{CONV_SENSE}$.	R/W Word	Y	L11		Y	0.0 0x8000	52
MFR_IOUT_CAL_GAIN_THETA	0xBA	Thermal resistance from inductor core to point measured by external temperature sensor.	R/W Word	Y	L11	°C/W	Y	0.0 0x8000	52
MFR_READ_IOUT	0xBB	Alternate data format for READ_IOUT. One LSB = 2.5mA.	R Word	Y	CF	2.5mA		NA	70
MFR_LTC_RESERVED_2	0xBC	Manufacturer reserved.	R/W Word	Y	Reg			NA	84
MFR_EE_UNLOCK	0xBD	Unlock user EEPROM for access by MFR_EE_ERASE and MFR_EE_DATA commands.	R/W Byte	N	Reg			NA	44
MFR_EE_ERASE	0xBE	Initialize user EEPROM for bulk programming by MFR_EE_DATA.	R/W Byte	N	Reg			NA	44
MFR_EE_DATA	0xBF	Data transferred to and from EEPROM using sequential PMBus word reads or writes. Supports bulk programming.	R/W Word	N	Reg			NA	44
MFR_COMMAND_PLUS	0xC8	Alternate access to block read and other data. Commands for all additional hosts.	R/W Word	N	Reg				29
MFR_DATA_PLUS0	0xC9	Alternate access to block read and other data. Data for additional host 0.	R/W Word	N	Reg				29
MFR_DATA_PLUS1	0xCA	Alternate access to block read and other data. Data for additional host 1.	R/W Word	N	Reg				29
MFR_CONFIG_LTC2974	0xD0	Configuration bits that are channel specific.	R/W Word	Y	Reg		Y	0x0080	34
MFR_CONFIG_ALL_LTC2974	0xD1	Configuration bits that are common to all pages.	R/W Word	N	Reg		Y	0x0F7B	34
MFR_FAULTB0_PROPAGATE	0xD2	Configuration that determines if a channel's faulted off state is propagated to the FAULTB0 pin.	R/W Byte	Y	Reg		Y	0x00	63
MFR_FAULTB1_PROPAGATE	0xD3	Configuration that determines if a channel's faulted off state is propagated to the FAULTB1 pin.	R/W Byte	Y	Reg		Y	0x00	63
MFR_PWRGD_EN	0xD4	Configuration that maps WDI/RESETB status and individual channel power good to the PWRGD pin.	R/W Word	N	Reg		Y	0x0000	56
MFR_FAULTB0_RESPONSE	0xD5	Action to be taken by the device when the FAULTB0 pin is asserted low.	R/W Byte	N	Reg		Y	0x00	63
MFR_FAULTB1_RESPONSE	0xD6	Action to be taken by the device when the FAULTB1 pin is asserted low.	R/W Byte	N	Reg		Y	0x00	63

PMBUS COMMAND SUMMARY

Summary Table

COMMAND NAME	CMD CODE	DESCRIPTION	TYPE	PAGED	DATA FORMAT	UNITS	EEPROM	DEFAULT VALUE: FLOAT HEX	REF PAGE
MFR_IOUT_PEAK	0xD7	Maximum measured value of READ_IOUT.	R Word	Y	L11	A		NA	70
MFR_IOUT_MIN	0xD8	Minimum measured value of READ_IOUT.	R Word	Y	L11	A		NA	70
MFR_CONFIG2_LTC2974	0xD9	Configuration bits that are channel specific	R/W Byte	N	Reg		Y	0x00	34
MFR_CONFIG3_LTC2974	0xDA	Configuration bits that are channel specific	R/W Byte	N	Reg		Y	0x00	34
MFR_RETRY_DELAY	0xDB	Retry interval during FAULT retry mode.	R/W Word	N	L11	ms	Y	200 0xF320	58
MFR_RESTART_DELAY	0xDC	Delay from actual CONTROL active edge to virtual CONTROL active edge.	R/W Word	N	L11	ms	Y	400 0xFB20	55
MFR_VOUT_PEAK	0xDD	Maximum measured value of READ_VOUT.	R Word	Y	L16	V		NA	70
MFR_VIN_PEAK	0xDE	Maximum measured value of READ_VIN.	R Word	N	L11	V		NA	70
MFR_TEMPERATURE_1_PEAK	0xDF	Maximum measured value of READ_TEMPERATURE_1.	R Word	Y	L11	°C		NA	70
MFR_DAC	0xE0	The code of the 10-bit DAC.	R/W Word	Y	Reg			0x0000	48
MFR_POWERGOOD_ASSERTION_DELAY	0xE1	Power-good output assertion delay.	R/W Word	N	L11	ms	Y	100 0xEB20	56
MFR_WATCHDOG_T_FIRST	0xE2	First watchdog timer interval.	R/W Word	N	L11	ms	Y	0 0x8000	56
MFR_WATCHDOG_T	0xE3	Watchdog timer interval.	R/W Word	N	L11	ms	Y	0 0x8000	56
MFR_PAGE_FF_MASK	0xE4	Configuration defining which channels respond to global page commands (PAGE=0xFF).	R/W Byte	N	Reg		Y	0x0F	29
MFR_PADS	0xE5	Current state of selected digital I/O pads.	R/W Word	N	Reg			NA	65
MFR_I2C_BASE_ADDRESS	0xE6	Base value of the I ² C/SMBus address byte.	R/W Byte	N	Reg		Y	0x5C	10x0215
MFR_SPECIAL_ID	0xE7	Manufacturer code for identifying the LTC2974.	R Word	N	Reg		Y	0x0214	83
MFR_SPECIAL_LOT	0xE8	Customer dependent codes that identify the factory programmed user configuration stored in EEPROM. Contact factory for default value.	R Byte	Y	Reg		Y	NA	83
MFR_VOUT_DISCHARGE_THRESHOLD	0xE9	Coefficient used to multiply VOUT_COMMAND in order to determine V _{OUT} off threshold voltage.	R/W Word	Y	L11		Y	2.0 0xC200	48
MFR_FAULT_LOG_STORE	0xEA	Command a transfer of the fault log from RAM to EEPROM.	Send Byte	N				NA	74
MFR_FAULT_LOG_RESTORE	0xEB	Command a transfer of the fault log previously stored in EEPROM back to RAM.	Send Byte	N				NA	74
MFR_FAULT_LOG_CLEAR	0xEC	Initialize the EEPROM block reserved for fault logging and clear any previous fault logging locks.	Send Byte	N				NA	74
MFR_FAULT_LOG_STATUS	0xED	Fault logging status.	R Byte	N	Reg		Y	NA	74

PMBUS COMMAND DESCRIPTION

The following example illustrates configuring an LTC2974 with one master channel and three slaves.

Master channel 0

TON_DELAY = Ton_delay_master

TON_RISE = Ton_rise_master

TOFF_DELAY = Toff_delay_master

Mfr_track_en_chan0 = 0

Slave channel n

TON_DELAY = Ton_delay_slave

TON_RISE = Ton_delay_master + Ton_rise_slave

TOFF_DELAY = Toff_delay_master + T_off_delay_slave

Mfr_track_en_chan0 = 1

Where:

Ton_delay_master – Ton_delay_slave > RUN to TRACK setup time

Toff_delay_slave > time for master supply to fall.

The system response to a control pin toggle is illustrated in Figure 18.

The system response to a UV fault on a slave channel is illustrated in Figure 19.

MFR_CONFIG_ALL_LTC2974

This command is used to configure parameters that are common to all channels on the IC. They may be set or reviewed from any PAGE setting.

MFR_CONFIG_ALL_LTC2974 Data Contents

BIT(S)	SYMBOL	OPERATION
b[15:12]	Reserved	Don't care. Always returns 0.
b[11]	Mfr_config_all_pwrzd_off_uses_uv	Selects PWRGD de-assertion source for all channels. 0: PWRGD is de-asserted based on V_{OUT} being below or equal to POWER_GOOD_OFF. This option uses the ADC. Response time is approximately 100ms to 200ms. 1: PWRGD is de-asserted based on V_{OUT} being below or equal to VOUT_UV_LIMIT. This option uses the high speed supervisor. Response time is approximately 12 μ s.
b[10]	Mfr_config_all_fast_fault_log <div style="border: 1px solid red; padding: 2px; display: inline-block; color: red;">Reserved</div>	Controls number of ADC readings completed before transferring fault log memory to EEPROM. 0: All ADC telemetry values will be updated before transferring fault log to EEPROM. Slower. 1: Telemetry values will be transferred from fault log to EEPROM within 24ms after detecting fault. Faster.
b[9]	Mfr_config_all_control3_pol	Selects active polarity of CONTROL3 pin 0: Active low (pull pin low to start unit). 1: Active high (pull pin high to start unit).
b[8]	Mfr_config_all_control2_pol	Selects active polarity of CONTROL2 pin 0: Active low (pull pin low to start unit). 1: Active high (pull pin high to start unit).

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